NSN 5962-01-114-1476

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-114-1476
Body Length:
Between 1.385 inches and 1.425 inches
Body Width:
Between 0.565 inches and 0.590 inches
Body Height:
Between 0.110 inches and 0.160 inches
Maximum Power Dissipation Rating:
748.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and w/decoded output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
9 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Test Data Document:
13973-839222 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Fiig: A458a0

Demilitarization: Yes - demil/mli